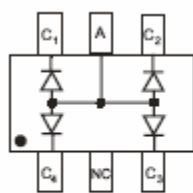
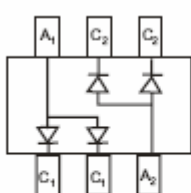
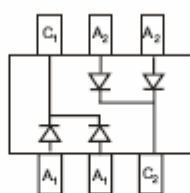
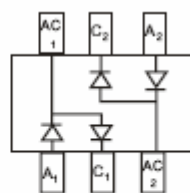
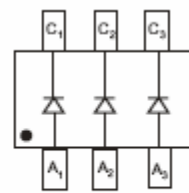


**SOT-363 Plastic-Encapsulate Diode****MMBD4448HAQW/ADW/CDW/SDW/TW Diode****SOT-363****FEATURES**

- Fast Switching Speed
- Ultra-Small Surface Mount Package
- For General Purpose Switching Applications
- High Conductance Power dissipation

Marking: KA5
MMBD4448HAQWMarking: KA6
MMBD4448HADWMarking: KA7
MMBD4448HCDWMarking: KAB
MMBD4448HSDWMarking: KAA
MMBD4448HTW**Maximum Ratings** @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	80	V
RMS Reverse Voltage	$V_{R(RMS)}$	57	V
Forward Continuous Current (Note 1)	I_{FM}	500	mA
Average Rectified Output Current (Note 1)	I_O	250	mA
Non-Repetitive Peak Forward Surge Current @ $t = 1.0\mu\text{s}$ @ $t = 1.0\text{s}$	I_{FSM}	4.0 2.0	A
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistant Junction to Ambient Air (Note 1)	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	80	—	V	$I_R = 100\mu\text{A}$
Forward Voltage (Note 2)	V_F	0.62 — — —	0.72 0.855 1.0 1.25	V	$I_F = 5.0\text{mA}$ $I_F = 10\text{mA}$ $I_F = 100\text{mA}$ $I_F = 150\text{mA}$
Reverse Current (Note 2)	I_R	—	100 50 30 25	nA μA μA nA	$V_R = 70\text{V}$ $V_R = 75\text{V}, T_J = 150^\circ\text{C}$ $V_R = 25\text{V}, T_J = 150^\circ\text{C}$ $V_R = 20\text{V}$
Total Capacitance	C_T	—	3.5	pF	$V_R = 6\text{V}, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}	—	4.0	ns	$V_R = 6\text{V}, I_F = 5\text{mA}$

Notes: 2. Short duration test pulse used to minimize self-heating effect.

Typical Characteristics

MMBD4448AQW/ADW/CDW/SDW/TW

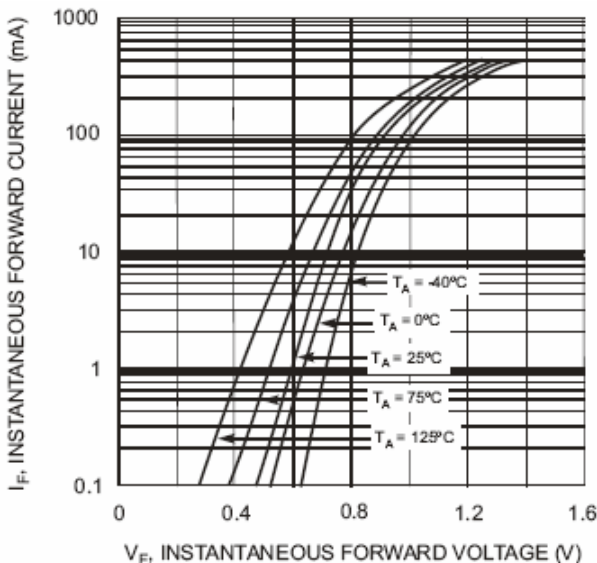


Fig. 1 Typical Forward Characteristics

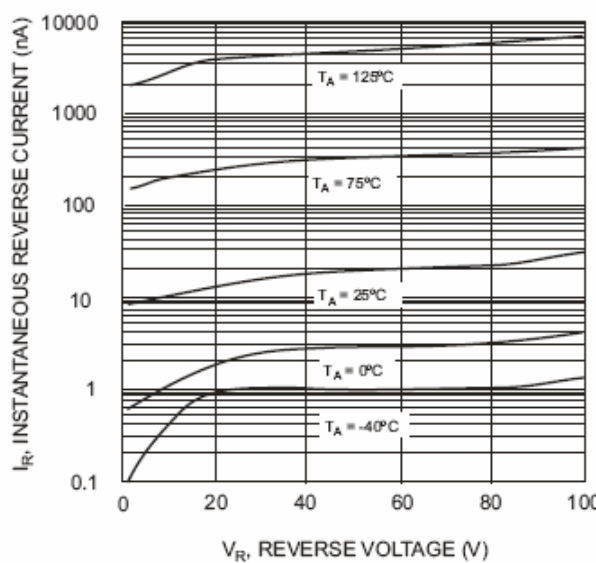


Fig. 2 Typical Reverse Characteristics

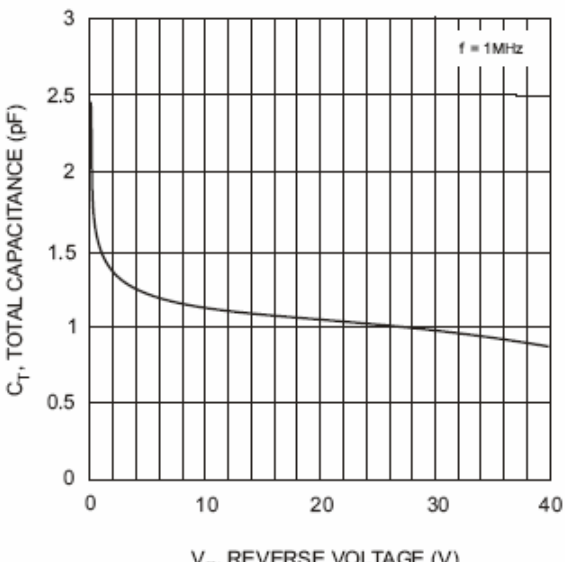


Fig. 3 Typical Capacitance vs. Reverse Voltage

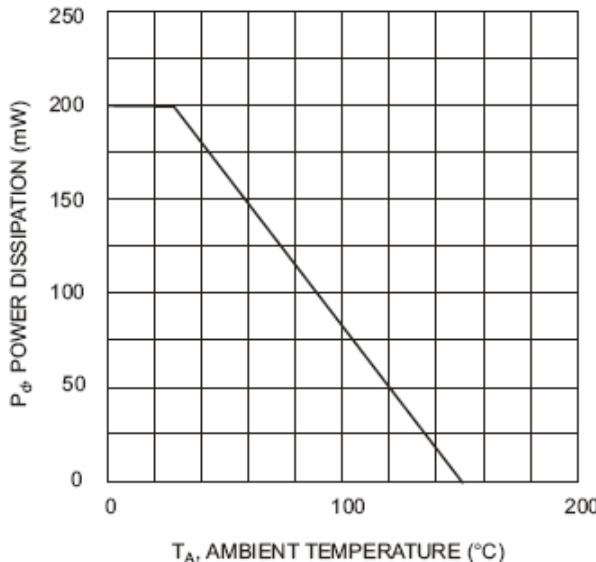


Fig. 4 Power Derating Curve, Total Package

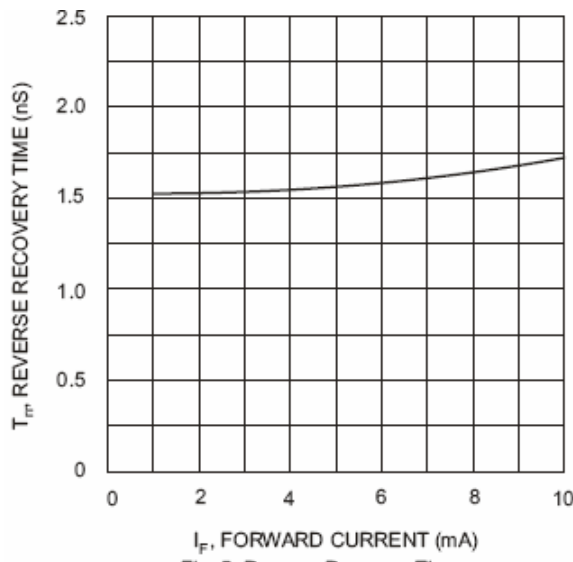


Fig. 5 Reverse Recovery Time vs. Forward Current